NSN 5961-00-369-7646

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.200 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.090 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
D0-35
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
55.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
200.00 milliamperes source cutoff current absolute
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector absolute
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
80131-release5453 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0